

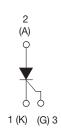
## VS-40TPS...PbF Series, VS-40TPS...-M3 Series

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Vishay Semiconductors

## Thyristor High Voltage, Phase Control SCR, 40 A





35 A

800 V, 1200 V

1.45 V

150 mA

-40 °C to +125 °C

TO-247AC

Single SCR

TO	-247A	C

 $I_{T(AV)}$ 

 $V_{DRM}/V_{RRM}$ 

 $V_{TM}$ 

 $I_{GT}$ 

 $T_{\mathsf{J}}$ 

Package

Circuit configuration

PRIMARY CHARACTERISTICS

### **FEATURES**

- Designed and qualified according JEDEC®-JESD 47
- Low I<sub>GT</sub> parts available
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHSCOMPLIANT **HALOGEN FREE** 

#### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-40TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I <sub>T(AV)</sub>	Sinusoidal waveform	35	^			
I <sub>RMS</sub>		55	Α Α			
V <sub>RRM</sub> /V <sub>DRM</sub>		800 to 1200	V			
I <sub>TSM</sub>		600	A			
V <sub>T</sub>	40 A, T <sub>J</sub> = 25 °C	1.45	V			
dV/dt		1000	V/µs			
dl/dt		100	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA			
VS-40TPS08APbF, VS-40TPS08A-M3	800	900				
VS-40TPS08PbF, VS-40TPS08-M3	800	900	10			
VS-40TPS12APbF, VS-40TPS12A-M3	1200	1300	10			
VS-40TPS12PbF, VS-40TPS12-M3	1200	1300				



Maximum peak on-state voltage

Maximum holding current

Maximum latching current

40TPS12A

40TPS12

Maximum rate of rise of turned-on current

Maximum reverse and direct leakage current

Maximum rate of rise of off-state voltage

Maximum rate of rise of off-state voltage

# VS-40TPS...PbF Series, VS-40TPS...-M3 Series

Anode supply = 6 V, resistive load, initial  $T_J$  = 1 A,  $I_T$  = 25 °C

 $T_J = T_J$  maximum, linear to 80 %  $V_{DRM},\,R_g$  - k = 100  $\Omega$ 

 $V_R = Rated V_{RRM}/V_{DRM}$ 

Anode supply = 6 V, resistive load, T<sub>J</sub> = 25 °C

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1.85

100

200

300

0.5

10

500

1000

٧

A/μs

mΑ

V/µs

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 79 °C, 180° conduction half sine wave	Э	35			
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>			55	А		
Maximum peak, one-cycle	L	10 ms sine pulse, rated V <sub>RRM</sub> applied		500			
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied	la iti al	600			
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	Initial $T_{.1} = T_{.1} max.$	1250	A <sup>2</sup> s		
Maximum i-t for fusing		10 ms sine pulse, no voltage reapplied	IJ – IJIIIax.	1760			
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied		17 600	A²√s		
Low level value of threshold voltage	V <sub>T(TO)1</sub>			1.02	V		
High level value of threshold voltage	V <sub>T(TO)2</sub>	T <sub>J</sub> = 125 °C		1.23	V		
Low level value of on-state slope resistance	r <sub>t1</sub>			9.74	m()		
High level value of on-state slope resistance	r <sub>t2</sub>			7.50	mΩ		

110 A,  $T_J = 25$  °C

 $T_J = 25 \, ^{\circ}C$ 

 $T_J = 25 \, ^{\circ}C$ 

 $T_J = 125$  °C

 $V_{TM}$ 

dI/dt

 $\mathsf{I}_\mathsf{H}$ 

 $I_{\mathsf{L}}$ 

 $I_{RRM}/I_{DRM}$ 

dV/dt

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum peak gate power	$P_{GM}$			10	W	
Maximum average gate power	P <sub>G(AV)</sub>			2.5	۷V	
Maximum peak gate current	$I_{GM}$			2.5	Α	
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	V	
		T <sub>J</sub> = - 40 °C	Anada sunak CV	4.0		
Maximum required DC gate voltage to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	2.5	V	
		T <sub>J</sub> = 125 °C	- resistive load	1.7		
		T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	270	- mA	
Maximum required DC gets as great to trigger		T <sub>J</sub> = 25 °C		150		
Maximum required DC gate current to trigger	I <sub>GT</sub>	T <sub>J</sub> = 125 °C		80		
		T <sub>J</sub> = 25 °C, for 40TPSAPbF and 40TPSA-M3		40	1	
Maximum DC gate voltage not to trigger for 40TPS12	$V_{GD}$	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		0.25	V	
Maximum DC gate current not to trigger for 40TPS12	I <sub>GD</sub>			6	mA	
Maximum DC gate voltage not to trigger for 40TPS12A	$V_{GD}$	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value		0.15	٧	
Maximum DC gate current not to trigger for 40TPS12A	I <sub>GD</sub>			1	mA	

# VS-40TPS...PbF Series, VS-40TPS...-M3 Series

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	PARAMETER		TEST CONDITIONS	VALUES	UNITS		
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +125	°C		
Maximum thermal resistar junction to case	nce,	R <sub>thJC</sub>	DC operation	0.6			
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DC operation		°C/W		
Maximum thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2			
Approximate weight				6	g		
Approximate weight				0.21	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque maximur				12 (10)	(lbf·in)		
Marking device				40TPS08A			
			Coop at the TO 247AC	40TPS12A			
			Case style TO-247AC	40TPS08			
					40TPS12		

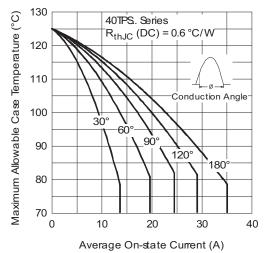


Fig. 1 - Current Rating Characteristics

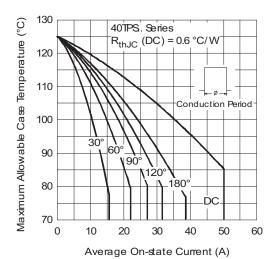


Fig. 2 - Current Rating Characteristics

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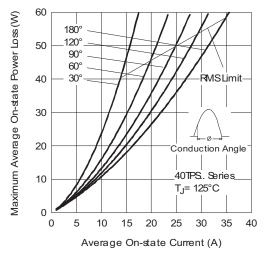


Fig. 3 - On-State Power Loss Characteristics

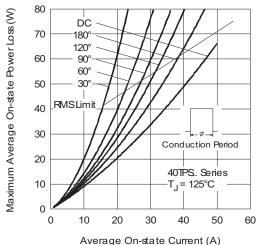
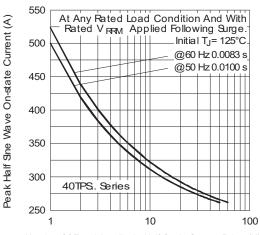


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current

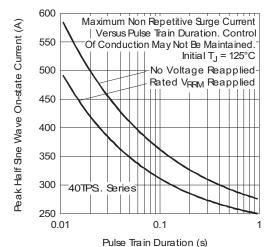


Fig. 6 - Maximum Non-Repetitive Surge Current

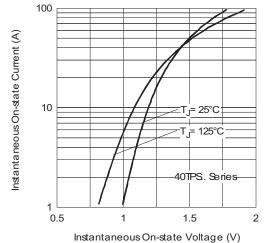


Fig. 7 - On-State Voltage Drop Characteristics

Instantaneous Gate Voltage (V)

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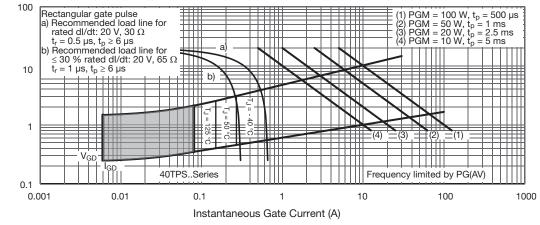


Fig. 8 - Gate Characteristics

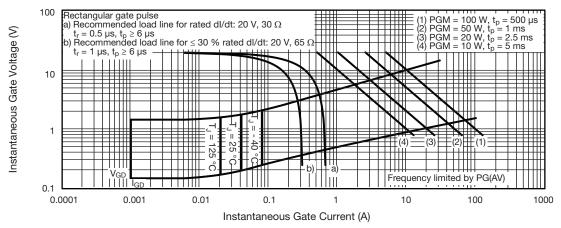


Fig. 9 - Gate Characteristics, 40TPS..A Series

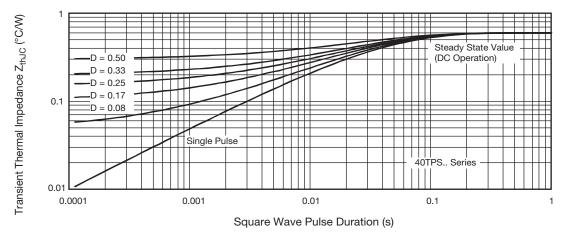


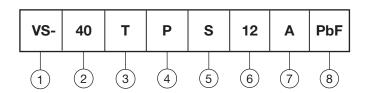
Fig. 10 - Thermal Impedance Z<sub>thJC</sub> Characteristics

## VS-40TPS...PbF Series, VS-40TPS...-M3 Series

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#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

**2** - Current rating (40 = 40 A)

Circuit configuration:

T = thyristor

4 - Package:

8

P = TO-247AC

5 - Type of silicon:

S = standard recovery rectifier

08 = 800 V 12 = 1200 V

6 - Voltage ratings

• None = standard lgt selection

- Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

• A = low I<sub>GT</sub> selection 40 mA maximum

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

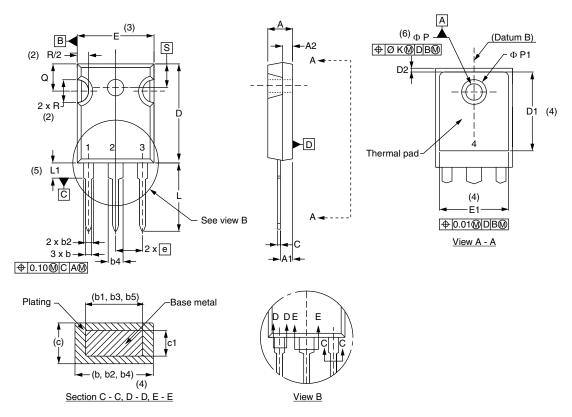
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-40TPS08APbF	25	500	Antistatic plastic tubes			
VS-40TPS08A-M3	25	500	Antistatic plastic tubes			
VS-40TPS08PbF	25	500	Antistatic plastic tubes			
VS-40TPS08-M3	25	500	Antistatic plastic tubes			
VS-40TPS12APbF	25	500	Antistatic plastic tubes			
VS-40TPS12A-M3	25	500	Antistatic plastic tubes			
VS-40TPS12PbF	25	500	Antistatic plastic tubes			
VS-40TPS12-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95542</u>				
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226		
	TO-247AC-M3	www.vishay.com/doc?95007		

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### TO-247AC - 50 mils L/F

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.35	0.020	0.053		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	1		
е	5.46	BSC	0.215	BSC		
ØK	0.254		0.0	10		
L	14.20	16.10	0.559	0.634		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	7.39	-	0.291		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217	BSC		

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$  Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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